EFC4621R

Power MOSFET 24V, 9A, 18mΩ N-Channel Dual EFCP



Features

- 2.5V drive
- Common-drain type
- 2KV ESD HBM

Applications

• Lithium-ion battery charging and discharging switch

Specifications

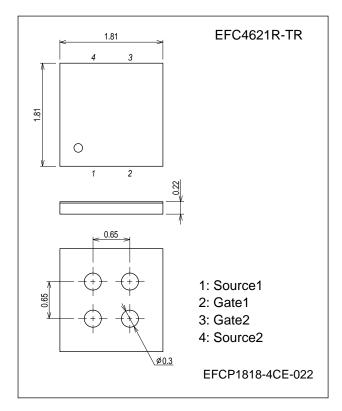
Absolute Maximum Ratings at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Source to Source Voltage	VSSS		24	V
Gate to Source Voltage	VGSS		±12	V
Source Current (DC)	IS		9	А
Source Current (Pulse)	ISP	PW≤10µs, duty cycle≤1%	60	А
Total Dissipation	Рт	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)



Ordering & Package Information

•	-			
Device	Package	Shipping	note	
EFC4621R-TR	EFCP	5000 pcs. / reel	Pb-Free and Halogen-Free	

Packing Type: TR

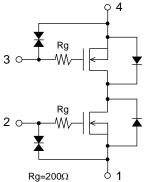
• Protection diode in

• Halogen free compliance

Marking

0

Electrical Connection



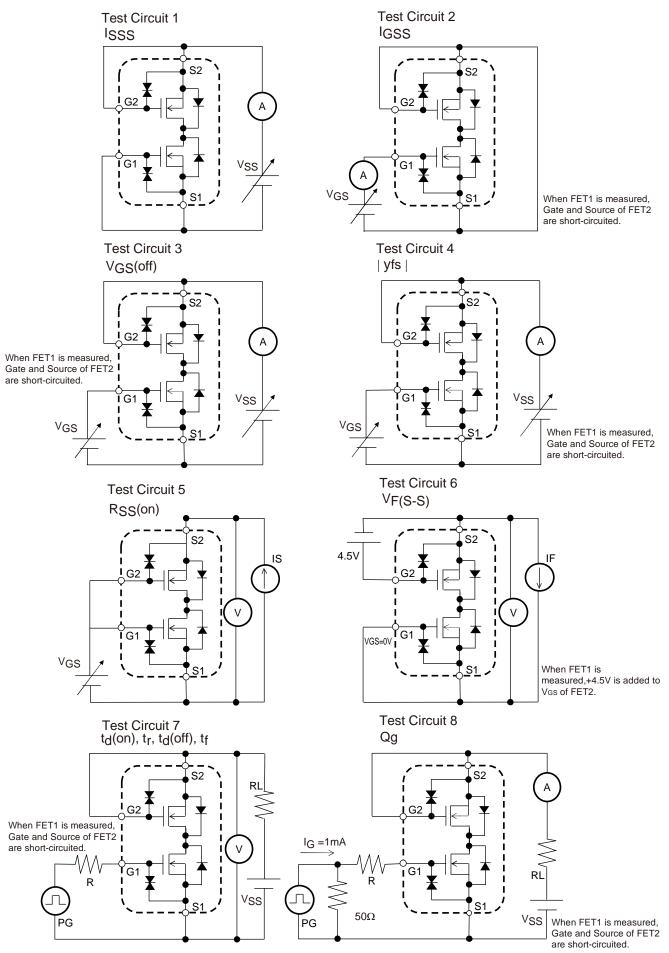


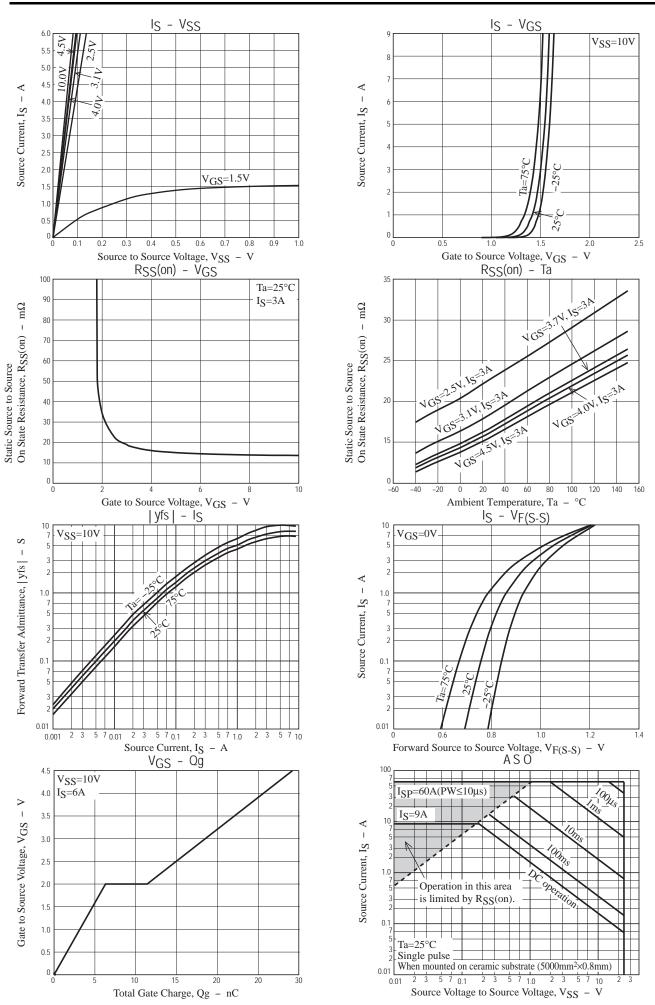
Electrical Characteristics at $Ta = 25^{\circ}C$

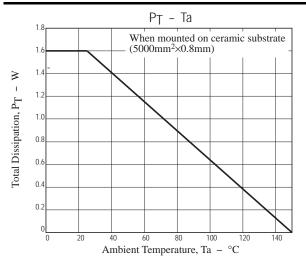
5				Ratings			
Parameter Symbol Conditions		ons	min	typ	max	Unit	
Source to Source Breakdown Voltage	V(BR)SSS	I _S =1mA, V _{GS} =0V	Test Circuit 1	24			V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =20V, V _{GS} =0V	Test Circuit 1			1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1	μA
Cutoff Voltage	V _{GS} (off)	V _{SS} =10V, I _S =1mA	Test Circuit 3	0.5		1.3	V
Forward Transfer Admittance	yfs	V _{SS} =10V, I _S =3A	Test Circuit 4		7.3		S
	R _{SS} (on)1	IS=3A, VGS=4.5V	Test Circuit 5	10.8	15.5	18	mΩ
	R _{SS} (on)2	IS=3A, VGS=4.0V	Test Circuit 5	11.1	16	19	mΩ
Static Source to Source On-State Resistance	R _{SS} (on)3	IS=3A, VGS=3.7V	Test Circuit 5	11.5	16.5	20	mΩ
Resistance	R _{SS} (on)4	I _S =3A, V _{GS} =3.1V	Test Circuit 5	12.5	18	23.5	mΩ
	R _{SS} (on)5	IS=3A, VGS=2.5V	Test Circuit 5	14.9	23	30	mΩ
Turn-ON Delay Time	t _d (on)				340		ns
Rise Time	tr	V _{SS} =10V, V _{GS} =4.5V, I _S =3A Test Circuit 7			600		ns
Turn-OFF Delay Time	t _d (off)				26000		ns
Fall Time	tf				28000		ns
Total Gate Charge	Qg	V _{SS} =10V, V _{GS} =4.5V, Is	=9A Test Circuit 8		29		nC
Forward Source to Source Voltage	VF(S-S)	IS=3A, VGS=0V	Test Circuit 6		0.77	1.2	V

EFC4621R

Test circuits are example of measuring FET1 side



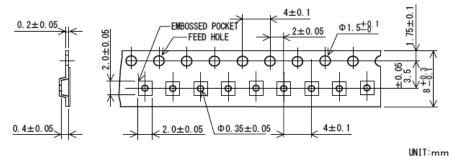




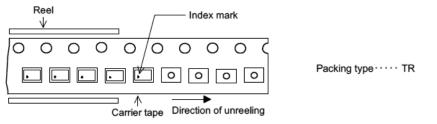
Taping Specification EFC4621R-TR

1. Taping Configuration

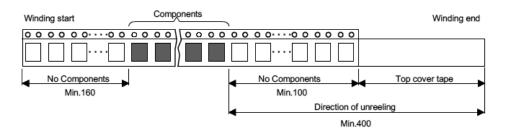
1-1.Carrier Tape Size (unit:mm)



1-2. Device Placement Direction



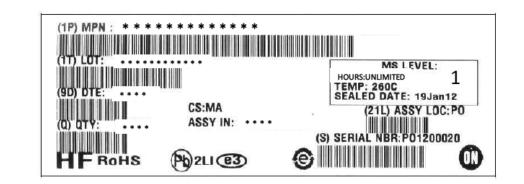
1-3 .Leader portion and Trailer portion (unit:mm)



Packing Format

Carrier Tape code	Package code	Maximum Number of devices contained. (pcs.)		Packing Format		
		Reel	Inner box		Inner box BOX(C-1)	
2020X04	EFCP1818-4CE-022	5,000	25,000		5reels contained. Dimensions:mm 183×72×185	

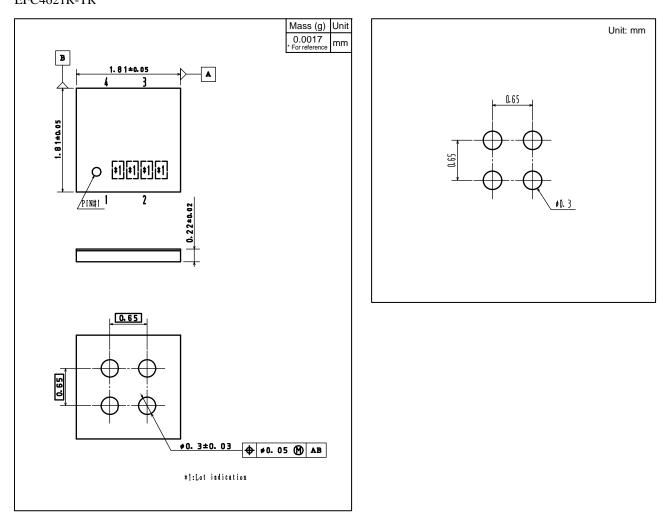
MPN Label



Packing Method



Outline Drawing EFC4621R-TR



Land Pattern Example

Note on usage : Since the EFC4621R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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